RH137H AND RH137K NEGATIVE ADJUSTABLE REGULATOR DICE

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FOR OFFICIAL USE ONLY

RH137H AND RH137K NEGATIVE ADJUSTABLE REGULATOR DICE

	REVISION RECORD	
REV	DESCRIPTION	DATE
Ι	Page 16, Changed RH Canned Sample Table for Qualifying Dice Sales: Subgroup 6 Sample Size Series changed from 45 (3) to 65 (3). First note had the Sample Size Series from "15%" to "10%".	7/2/13
J	Updated Die Sales table on pg 16.	6/3/15
K	Update burn-in circuit on pg 9 & 10 to reflect changes to burn-in ambient temperature and addition of thermal shutdown temperature.	08/29/17
L	To remove SI and change Linear Technology to Analog Device	01/04/21
Μ	To remove Philippinnes	3/19/21

1.0 SCOPE:

1.1 This specification defines the performance and test requirements for a microcircuit processed to a space level manufacturing flow.

2.0 APPLICABLE DOCUMENTS:

2.1 <u>Government Specifications and Standards</u>: the following documents listed in the Department of Defense Index of Specifications and Standards, of the issue in effect on the date of solicitation, form a part of this specification to the extent specified herein.

SPECIFICATIONS:

MIL-PRF-38535	Integrated Circuits (Microcircuits) Manufacturing, General Specification for
MIL-STD-883	Test Method and Procedures for Microcircuits
MIL-STD-1835	Microcircuits Case Outlines

2.2 <u>Order of Precedence:</u> In the event of a conflict between the documents referenced herein and the contents of this specification, the order of precedence shall be this specification, MIL-PRF-38535 and other referenced specifications.

3.0 REQUIREMENTS:

- 3.1 <u>General Description</u>: This specification details the requirements for the RH137, Negative Adjustable Regulator Dice and Element Evaluation Test Samples, processed to space level manufacturing flow as specified herein.
- 3.2 <u>Part Number</u>:
 - 3.2.1 OPTION 1 RH137H DICE
 - 3.2.2 OPTION 2 RH137K DICE
- 3.3 <u>Special Handling of Dice</u>: Rad Hard dice require special handling as compared to standard IC dice. Rad Hard dice are susceptible to surface damage due to the absence of silicon nitride passivation that is present on most standard dice. Silicon nitride protects the dice surface from scratches with its hard and dense properties. The passivation on Analog Devices Rad Hard dice is silicon dioxide, which is much "softer" than silicon nitride. During the visual and preparation for shipment, ESD safe Tweezers are used and only the edge of the die are touched.

ADI recommends that dice handling be performed with extreme care so as to protect the die surface from scratches. If the need arises to move the die in or out of the chip shipment tray (waffle pack), use an ESD-Safe-Plastic-tipped Bent Metal Vacuum Probe, preferably .020" OD x .010" ID (for use with tiny parts). The wand should be compatible with continuous air vacuums. The tip material should be static dissipative Delrin (or equivalent) plastic.

During die attach, care must be exercised to ensure no tweezers, or other equipment, touch the top of the dice.

3.4 <u>The Absolute Maximum Ratings</u>:

 Power Dissipation
 Internally Limited

 Input-Output Voltage Differential
 30V

Operating Junction Temperature Range						-55°C to 150°C
Storage Temperature Range						-65°C to 150°C
Lead Temperature (Soldering, 10 sec)		•		•		300°C

- 3.5 <u>Design, Construction, and Physical Dimensions</u>: Detail design, construction, physical dimensions, and electrical requirements shall be specified herein.
- 3.6 <u>Outline Dimensions and Pad Functions</u>: Dice outline dimensions, pad functions, and locations shall be specified in **Figure 1**.
- 3.7 Radiation Hardness Assurance (RHA):
 - 3.7.1 The manufacturer shall perform a lot sample test as an internal process monitor for total dose radiation tolerance. The sample test is performed with MIL-STD-883 TM1019 Condition A as a guideline.
 - 3.7.2 For guaranteed radiation performance to MIL-STD-883, Method 1019, total dose irradiation, the manufacturer will provide certified RAD testing and report through an independent test laboratory when required as a customer purchase order line item.
 - 3.7.3 Total dose bias circuit is specified in **Figure 2**.
- 3.8 <u>Wafer (or Dice) Probe</u>: Dice shall be 100% probed at Ta = +25°C to the limits shown in **Table I** herein. All reject dice shall be removed from the lot. This testing is normally performed prior to dicing the wafer into chips. Final specifications after assembly are sample tested during the element evaluation.
- 3.9 <u>Wafer Lot Acceptance</u>: Wafer lot acceptance shall be in accordance with MIL-PRF-38535, Appendix A, except for the following: Top side glassivation thickness shall be a **minimum of 4KÅ**.
- 3.10 <u>Wafer Lot Acceptance Report</u>: SEM is performed per MIL-STD-883, Method 2018. Copies of SEM photographs shall be supplied with the Wafer Lot Acceptance Report as part of a Space Data Pack when specified as a customer purchase order line item.
- 3.11 <u>Traceability</u>: Wafer Diffusion Lot and Wafer traceability shall be maintained through Quality Conformance Inspection.
- 4.0 QUALITY CONFORMANCE INSPECTION: Quality Conformance Inspection shall consist of the tests and inspections specified herein.
- 5.0 SAMPLE ELEMENT EVALUATION: A sample from **each wafer supplying dice** shall be assembled and subjected to element evaluation per **Table III** herein.
 - 5.1 <u>100 Percent Visual Inspection</u>: All dice supplied to this specification shall be inspected in accordance with MIL-STD-883, Method 2010, Condition A. All reject dice shall be removed from the lot.
 - 5.2 <u>Electrical Performance Characteristics for Element Evaluation</u>: The electrical performance characteristics shall be as specified in **Table I** and **Table II** herein.
 - 5.3 <u>Sample Testing</u>: Each wafer supplying dice for delivery to this specification shall be subjected to element evaluation sample testing. No dice shall be delivered until all the lot sample testing has been performed and the results found to be acceptable unless the customer supplies a written approval for shipment prior to completion of wafer qualification as specified in this specification.
 - 5.4 <u>Part Marking of Element Evaluation Sample Includes</u>:

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	5.4.1	LTC Logo
	5.4.2	LTC Part Number
	5.4.3	Date Code
	5.4.4	Serial Number
	5.4.5	ESD Identifier per MIL-PRF-38535, Appendix A
	5.4.6	Diffusion Lot Number
	5.4.7	Wafer Number
5.5		<u>n Requirement</u> : Burn-In circuit for TO39 package is specified in Figure 3 and Burn-In circuit 3 package is specified in Figure 4 .

- 5.6 <u>Mechanical/Packaging Requirements</u>: Case Outline and Dimensions are in accordance with **Figure 5** and **Figure 6**.
- 5.7 <u>Terminal Connections</u>: The terminal connections shall be as specified in Figure 7 and Figure 8.
- 5.8 <u>Lead Material and Finish:</u> The lead material and finish shall be Kovar for device option 1 and Alloy 52 for device option 2, with hot solder dip (Finish letter A) in accordance with MIL-PRF-38535.

6.0 VERIFICATION (QUALITY ASSURANCE PROVISIONS)

- 6.1 <u>Quality Assurance Provisions</u>: Quality Assurance provisions shall be in accordance with MIL-PRF-38535. Analog Devices is a QML certified company and all Rad Hard candidates are assembled on qualified Class S manufacturing lines.
- 6.2 <u>Sampling and Inspection</u>: Sampling and Inspection shall be in accordance with **Table III** herein.
- 6.3 <u>Screening</u>: Screening requirements shall be in accordance with **Table III** herein.
- 6.4 <u>Deliverable Data</u>: Deliverable data that will ship with devices when a Space Data Pack is ordered:
 - 6.4.1 Lot Serial Number Sheets identifying all Canned Sample devices accepted through final inspection by serial number.
 - 6.4.2 100% attributes (completed element evaluation traveler).
 - 6.4.3 Element Evaluation variables data, including Burn-In and Op Life
 - 6.4.4 SEM photographs (3.10 herein)
 - 6.4.5 Wafer Lot Acceptance Report (3.9 herein)
 - 6.4.6 A copy of outside test laboratory radiation report if ordered
 - 6.4.7 Certificate of Conformance certifying that the devices meet all the requirements of this specification and have successfully completed the mandatory tests and inspections herein.

Note: Items 6.4.1 and 6.4.7 will be delivered as a minimum, with each shipment.

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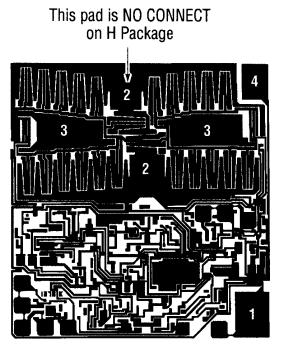
7.0 <u>Packaging Requirements</u>: Packaging shall be in accordance with Appendix A of MIL-PRF-38535. All dice shall be packaged in multicavity containers composed of conductive, anti-static, or static dissipative material with an external conductive field shielding barrier.

DICE OUTLINE DIMENSIONS AND PAD FUNCTIONS OPTION 1, RH137H DICE AND OPTION 2, RH137K DICE

PAD FUNCTION

ADJUST
 OUTPUT
 INPUT

4. OUTPUT SENSE (CONNECT TO OUTPUT)



 $85 \text{mils} \times 89 \text{mils}$

FIGURE 1

TOTAL DOSE BIAS CIRCUIT

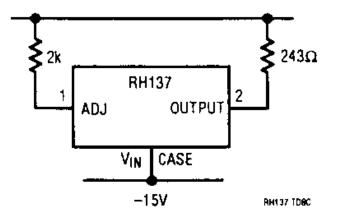
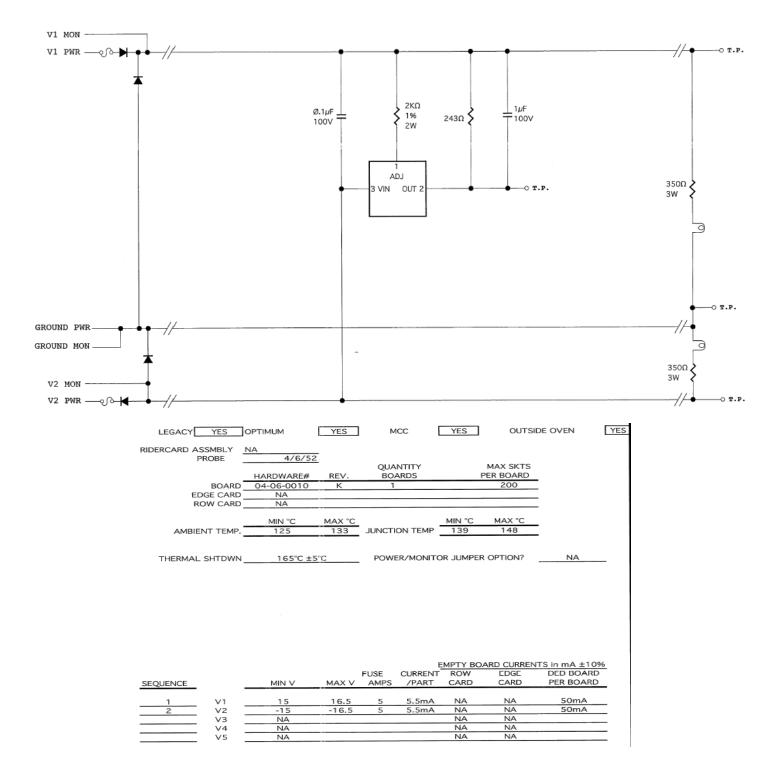


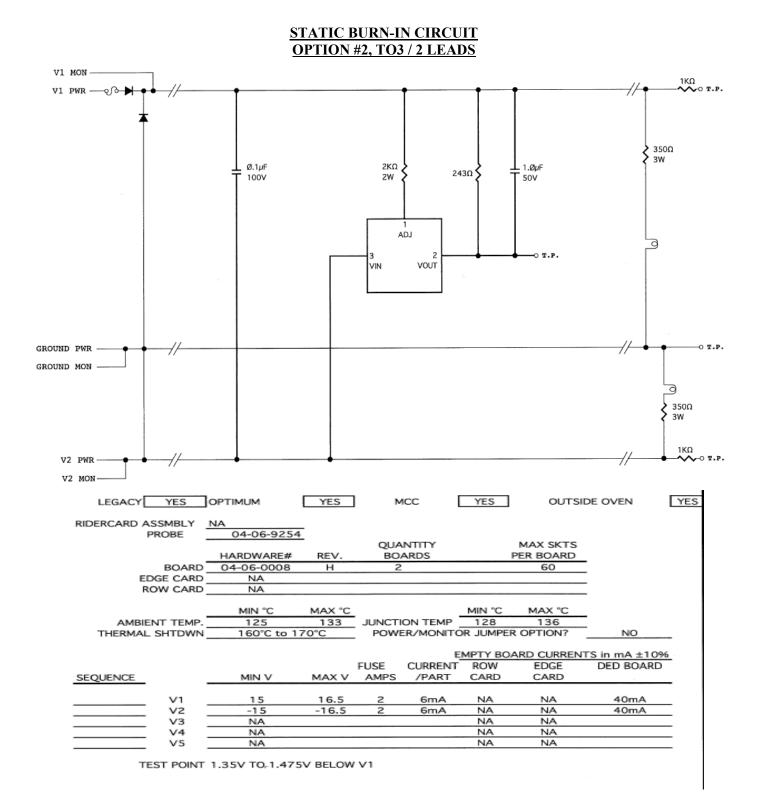
FIGURE 2

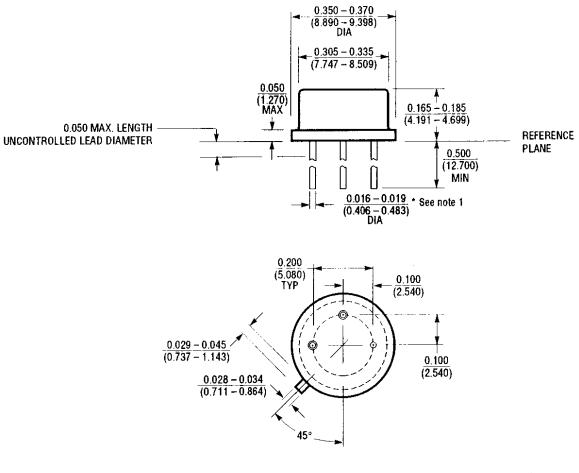
TO39 STATIC BURN-IN CIRCUIT OPTION 1, T039 METAL CAN / 3 LEADS

ANALOG DEVICES INC.

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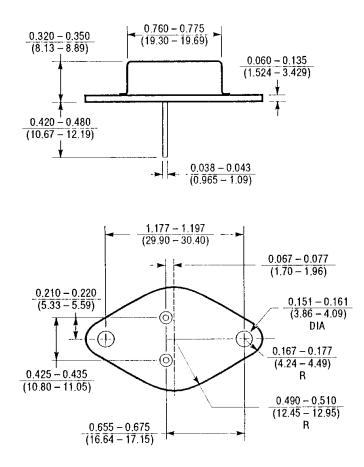
DEVICE OPTION # 1 (H) TO39 METAL CAN / 3 LEADS CASE OUTLINE

NOTE: 1. FOR SOLDER DIP LEAD FINISH, LEAD DIAMETER IS $\frac{0.016 - 0.024}{(0.406 - 0.610)}$

FIGURE 5

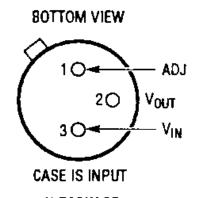
 $\theta ja = +150^{\circ}C/W$ $\theta jc = +40^{\circ}C/W$

DEVICE OPTION # 2 (K) TO3 METAL CAN / 2 LEADS CASE OUTLINE



 $\theta ja = +35^{\circ}C/W$ $\theta jc = +3^{\circ}C/W$

TERMINAL CONNECTIONSDEVICE OPTION #1, TO39 / 3 LEAD METAL CAN



H PACKAGE 3-LEAD TO-39 METAL CAN

FIGURE 7

DEVICE OPTION #2, TO3 / 2 LEAD METAL CAN

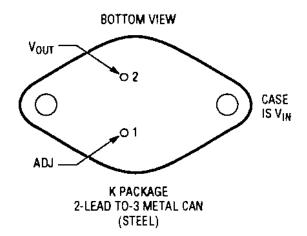


TABLE I DICE ELECTRICAL CHARACTERISTICS – Element Evaluation (Note 1)

			Ta =	25°C	
SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNITS
V _{REF}	Reference Voltage	$ V_{IN} - V_{OUT} = 5V$, $I_{OUT} = 10mA$ $3V \le V_{IN} - V_{OUT} \le 30V$, $10mA \le I_{OUT} \le 200mA$ $P \le P_{MAX}$	1.225 1.200	-1.275 -1.300	V V
ΔV _{OUT} ΔV _{IN}	Line Regulation	$3V \le V_{IN} - V_{OUT} \le 30V$		0.02	%/V
ΔV _{OUT} ΔΙ _{ΟUT}	Load Regulation	$10mA \le I_{OUT} \le I_{MAX}$, $ V_{OUT} \le 5V$ (Note 2) $10mA \le I_{OUT} \le I_{MAX}$, $ V_{OUT} \ge 5V$ (Note 2)		25 0.5	mV %
I _{ADJ}	Adjust Pin Current			100	μA
∆I _{ADJ}	Adjust Pin Current Change	$\begin{array}{l} 10\text{mA} \leq I_{\text{OUT}} \leq I_{\text{MAX}} \\ 3\text{V} \leq \text{V}_{\text{IN}} - \text{V}_{\text{OUT}} \leq 30\text{V} \end{array}$		5 5	Αц Αц
I _{MIN}	Minimum Load Current	V _{IN} - V _{OUT} = 30V V _{IN} - V _{OUT} = 3V		5 3	mA mA
	Current Limit	V _{IN} – V _{OUT} ≤ 15V H Package K Package	0.5 1.5		A
		V _{IN} – V _{OUT} = 30V H Package K Package	0.15 0.24		A

Note 1: Dice are probe tested at 25°C to the limits shown except for high current tests. Dice are tested under low current conditions which assure full load current specifications when assembled in packaging systems approved by Linear Technology. For absolute maximum ratings, typical specifications, performance curves and finished product specifications, please refer to the standard product RH data sheet.

Note 2: Testing is done using a pulsed low duty cycle technique. See thermal regulation specifications for output changes due to heating effects.

TABLE II ELECTRICAL CHARACTERISTICS (POSTIRRADIATION) (Notes 1 and 4)

SYMBOL	PARAMETER	CONDITIONS	NOTES		AD(Si) Max	20KRA Min	D(Si) MAX	50KR/ Min	AD(SI) Max	100KR/ Min	AD(Si) Max	200KR Min	AD(Si) MAX	UNITS
V _{REF}	Reference Voltage	$ V_{IN} - V_{OUT} \le 5V,$ OUT = 10mA		-1.225	-1.275	-1.225	-1.275	-1.225	-1.275	-1.225	-1.275	-1.22	-1.28	v
		$3V \le V_{IN} - V_{OUT} \le 30V,$ $10mA \le I_{OUT} \le I_{MAX}, P \le P_{MAX}$		-1.2	-1.3	-1.2	-1.3	-1.2	-1.3	-1.2	-1.3	-1.2	-1.3	v
ΔV _{OUT} ΔV _{IN}	Line Regulation	$3V \le V_{IN} - V_{OUT} \le 30V,$	2		0.02		0.02		0.02		0.02		0.02	%N
∆V _{OUT} ∆I _{OUT}	Load Regulation	10mA ≤ I _{OUT} ≤ I _{MAX} , V _{OUT} ≤ 5V	2		25		25		25		25		25	mV
		10mA ≤ I _{OUT} ≤ I _{MAX} , V _{OUT} ≥ 5V	2		0.5		0.5		0.5		0.5		0.5	%

NOTES:

• REMAINDER OF THE TABLE II ELECTRICAL CHARACTERISTICS (POST-IRRADIATION) AND NOTES ARE ON PAGE 14.

TABLE II ELECTRICAL CHARACTERISTICS (POST-IRRADIATION)(Notes 1 and 4) (Continued)

SYMBOL	PARAMETER	CONDITIONS	NOTES	10KR Min	AD(Si) Max	20KR/ Min	AD(Si) Max	50KR Min	AD(Si) Max	100KR Min	AD(Si) Max	200KR Min	AD(Si) Max	UNITS
I _{ADJ}	Adjust Pin Current				100		100		100		100		100	μA
ΔI _{ADJ}	Adjust Pin Current Change	$\begin{array}{l} 10\text{mA} \leq I_{\text{OUT}} \leq I_{\text{MAX}} \\ 3\text{V} \leq \left \text{V}_{\text{IN}} - \text{V}_{\text{OUT}} \right \leq 30\text{V} \end{array}$			5 5		5 5		5 5		5 5		5 5	μΑ μΑ
I _{MIN}	Minimum Load Current	$ V_{IN} - V_{OUT} = 30V$ $ V_{IN} - V_{OUT} \le 10V$			5 3		5 3		5 3		5 3		5 3	mA mA
	Current Limit H Package	V _{IN} – V _{OUT} ≤ 15V V _{IN} – V _{OUT} = 30V		0.5 0.15		0.5 0.15		0.5 0.15		0.5 0.15		0.5 0.15		A
		$\left V_{\text{IN}} - V_{\text{OUT}} \right \le 15V$ $\left V_{\text{IN}} - V_{\text{OUT}} \right = 30V$		1.5 0.24		1.5 0.24	· ·	1.5 0.24		1.5 0.24		1.5 0.24		A

Note 1: Unless otherwise specified, these specifications apply for $|V_{IN} - V_{OUT}| = 5V$; and $I_{OUT} = 0.1A$ for the H package (TO-39) and $I_{OUT} = 0.5A$ for the K package (TO-3) package. Although power dissipation is internally limited, these specifications are applicable for power

dissipations of 2W for the TO-39 and 20W for the TO-3. I_{MAX} is 0.2A for the TO-39 and 1.5A for the TO-3 package.

Note 2: Regulation is measured at a constant junction temperature using pulse testing with a low duty cycle. Changes in output voltage due to heating effects are covered under the specification for thermal regulation.

Note 3: Guaranteed by design, characterization or correlation to other tested parameters.

Note 4: $T_J = 25^{\circ}C$ unless otherwise noted.

Note 5: I_{SC} is tested at the ambient temperatures of 25°C and –55°C. I_{SC} cannot be tested at the maximum ambient temperature of 150°C due to the high power level required. I_{SC} specification at 150°C ambient is guaranteed by characterization and correlation to 25°C testing.

TABLE III RH ELEMENT EVALUATION TABLE QUALIFICATION OF DICE SALES

SUBGROUP K/S V 1 V K/S V 4 3 2 X X 5 X X X 6 X X X X X X X				RH CANNED SAMPLE TABLE FOR QUALIFYING DICE SALES MIL-ST MIL-ST MIL-ST MIL-ST MIL-ST MIL-ST MIL-ST OPERATION MIL-ST MIL-ST OPERATION METHOD SEM 2010 INTERNAL VISUAL (2nd OP) 2010 INTERNAL VISUAL (2nd OP) 2010 DIE SHEAR MONITOR 2010 BOND PULL MONITOR 2011 SOUT INTERNAL VISUAL (2nd OP) 2010 DIE SHEAR MONITOR 2010 BOND PULL MONITOR 2011 SOUT 2011 SOUT 2011 SOUT 2011 SOUT 2011 SOUT 2011 SOUT 2001 Internation 2001 Inteac 1014 1014	ING DICE SALES MIL-STE METHOD 2018 2010 2010 2011 1008 1010 2001 1014 1014 1014 1015 +	TD-883 CONDITION N/A A A A A A A A A C C C C C C C C C C C	QUANTITY (ACCEPT NUMBER) REF. METHOD 2018 FOR S/S 100% ASSEMBLED PARTS ONLY ASSEMBLED PARTS ONLY 45(0)
	×	 ×	Ļ	SKUSS LEAK	1014	ſ	
c	>	>		REPLACE ANY ASSEMBLY-RELATED REJECTS)			10/01
	×	×	-	PRE BURN-IN ELECT. READ & RECORD @ +125°C or +150°C, -55°C			
	×	×	E	3URN-IN: +125°C/240 hrs. or +150°C/120 hrs.	1015		
	×	×	-	°OST BURN-IN ELECT. READ & RECORD @ 25℃			
	×	×	_	POST BURN-IN ELECT. READ & RECORD @ +125°C or +150°C, -55°C			
		×		TOTAL IRRADIATION DOSE	1019	A	
	×	×		PRE OP-LIFE ELECTRICAL @ 25°C READ & RECORD			
	×	×		OPERATING LIFE: +125°C/1000 hrs. or +150°C/500 hrs.	1005	+ 125°c MINIMUM 1000 HOURS	
	×	×	П	POST OP-LIFE ELECT. (R & R @ 25°C, +125°C OR +150°C, -55°C			
7	×	×	X	WIRE BOND EVALUATION	2011		15(0) OR 25(1) - # of wires
NOTE:	LTC i	s not	t qua	LTC is not qualified to process to MIL-PRF-38534. This is an LTC imposed element evaluation	ment evaluatio	n that follows	
	MIL-: 5%,	STD-:	883 pt o	MIL-STD-883 test methods and conditions. Please note the quantity and accept number from Sample Size Series of 5%, accept on 0, and note that the actual sample and accept number does not begin until Subgroup 6 OP-LIFE.	ept number fro not begin until	m Sample Size Serie Subgroup 6 OP-LIFE	eries of IFE.
NOTE:	Tests	wit	hin S	Tests within Subgroup 5 may be performed in any sequence.			
NOTE:	LTC's	radi	atio	LTC's radiation tolerance (RH) die has a topside glassivation thickness of 4KA minimum.	minimum.		
NOTE:	Samp to ac relat	ole si com ed re	izes , mod egat	Sample sizes on the travelers may be larger than that indicated in the above table; however, the larger sample size to accommodate extra units for replacement devices in the event of equipment or operator error and for assembly related rejects in Subgroup 6, and for Wire Bond Evaluation, Surgroup 7. The larger sample size is at all times kept segregated and, if used for qualification, has all the required processing imposed.	table; howeve ent or operato larger sample imposed.	r, the larger sample size is r error and for assembly size is at all times	ole size is sembly ş